

ST8812FX

High voltage fast-switching NPN Power transistor

Features

- High voltage capability
- Very high switching speed
- Tight hfe control
- Large R.B.S.O.A.
- Fully insulated Package U.L. compliant for easy mounting

Applications

■ Switch mode power supplies for crt TV

Description

The ST8812FX is manufactured using latest Multi Epitaxial Planar technology with high voltage capability. It shows wide R.B.S.O.A. and high switching speed thanks to its Cellular Emitter structure with planar edge termination and deep base diffusion.



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing	
ST8812FX	ST8812FX	ISOWATT218FX	TUBE	

March 2006

Electrical ratings 1

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	1150	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	600	V
V _{EBO}	Emitte-Base Voltage (I _C = 0)	15	V
۱ _C	Collector Current	7	А
I _{CM}	Collector Peak Current (t _P < 5ms)	12	А
Ι _Β	Base Current	4	А
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$	50	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T _{STG}	Storage Temperature	-65 to 150	°C
TJ	Max. Operating Junction Temperature	150	°C

Table 1. Absolute maximum rating

Table 2. Thermal data

R _{thJ-case} Thermal Resistance Junction-Case Max 2.5 °C	Parameter	16,	Value	Uni
opere producils) - Ope	Thermal Resistance Junction-Case	Max	2.5	°C/
osolete Product(s)	(103		I
bsolete Product(s))*		
bsolete Product(S)				
bsolete Producia	*(5)			
bsolete Produ				
bsolete Proc	dv.			
bsolete F.	0100			
bsolete	A .			
05016				
10 ^{SU}	360			
	Sto			
	Sto			
10501	-	Parameter Thermal Resistance Junction-Case	Parameter Thermal Resistance Junction-Case Max	Parameter Value Thermal Resistance Junction-Case Max 2.5

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2 Electrical characteristics

(T_{CASE} = 25°C; unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 1150V V _{CE} = 1150V T _c = 125°C	;		1 2	mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 14V			1	mA
V _{CEO(sus)} Note: 1	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100mA	600			V
V _{CE(sat)} Note: 1	Collector-Emitter Saturation Voltage	$I_{C} = 4A \qquad I_{B} = 0.8A$ $I_{C} = 4A \qquad I_{B} = 1.2A$		90	3 1.5	V V
V _{BE(sat)} Note: 1	Base-Emitter Saturation Voltage	$I_{\rm C} = 4$ A $I_{\rm B} = 0.8$ A	81	0	1.3	V
h _{FE}	DC Current Gain	$I_{C} = 1A$ $V_{CE} = 5V$ $I_{C} = 5A$ $V_{CE} = 1V$ $V_{CE} = 5V$ $V_{CE} = 5V$	4.5	25 5	9	
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	$I_{C} = 4A$ $R_{BB} = 0$ $V_{Clamp} = 480V$ $V_{BE(off)} = -5V$ $I_{B1} = 0.8A$ $L_{C} = 220\mu H$ (See <i>Figure 8</i>)		1 60	1.6 120	μs ns

 Table 3.
 Electrical characteristics

Note: 1 Pulsed duration = $300 \,\mu$ s, duty cycle $\leq 1.5\%$.



2.1 Typical characteristics test circuit

Figure 1. DC current gain

Figure 2. DC current gain











1

0

3

4 $I_{C}(A)$

2

Figure 6. Inductive load fall time





Figure 7. Reverse biased S.O.A.







Figure 8. Inductive load switching test circuit



3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

obsolete Product(s). Obsolete Product(s)



ым		mm		inch		
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	5.30		5.70	0.209		0.224
С	2.80		3.20	0.110		0.126
D	3.10		3.50	0.122		0.138
D1	1.80		2.20	0.071		0.087
Е	0.80		1.10	0.031		0.043
F	0.65		0.95	0.026		0.037
F2	1.80		2.20	0.071		0.087
G	10.30		11.50	0.406		0.453
G1		5.45			0.215	AV.
Н	15.30		15.70	0.602		0.618
L	9.0		10.20	0.354	S	0.402
L2	22.80		23.20	0.898		0.913
L3	26.30		26.70	1.035		1.051
L4	43.20		44.40	1.701		1.748
L5	4.30		4.70	0.169		0.185
L6	24.30		24.70	0.957		0.972
L7	14.60		15.00	0.575		0.591
N	1.80		2.20	0.071		0.087
R	3.80		4.20	0.150		0.165
DIA	3.40		3.80	0.134		0.150





4 Revision History

Table 4. Revision history

Date	Revision	Changes
23-Feb-2006	1	Initial release.

obsolete Product(s). Obsolete Product(s)

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